

Emittance optimization for various machine parameters at PITZ.

PITZ 1.8 setup

Parameters for optimization

Optimization results for 1nC, 0.25, 0.1 nC, 0.02 nC and 2 nC bunch charges

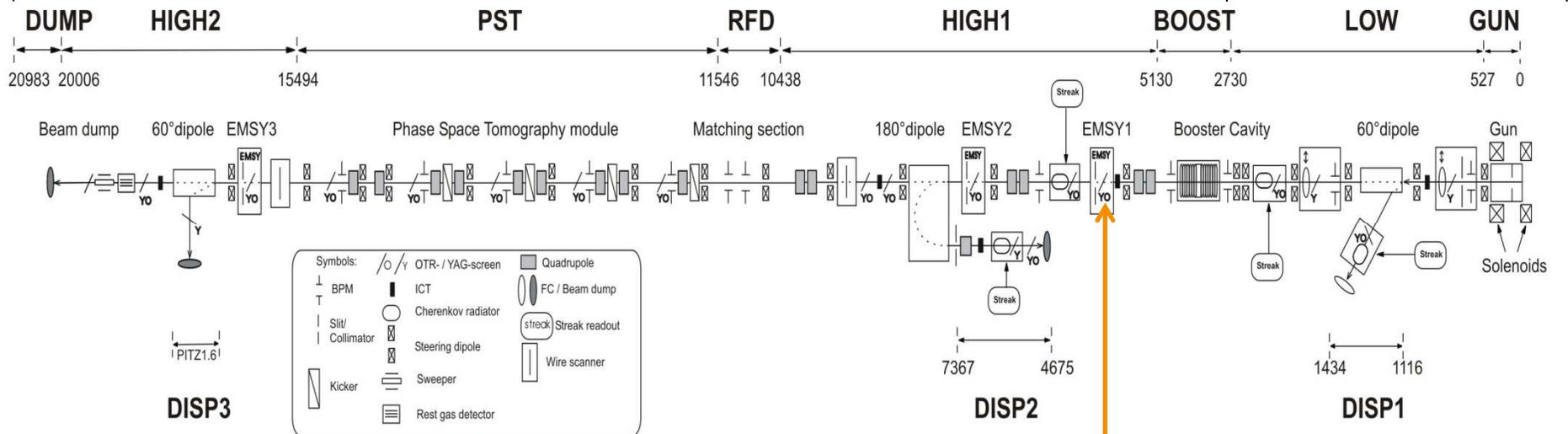
Summary

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Dresden, 04-08.03.2013

PITZ setup.

High energy part (up to ~ 25 MeV/c)

Low energy part (up to ~ 6.7 MeV/c)

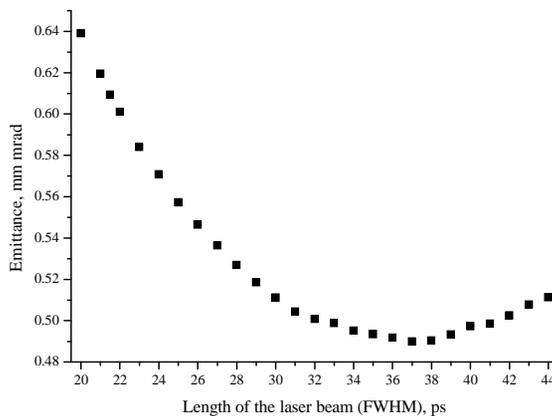
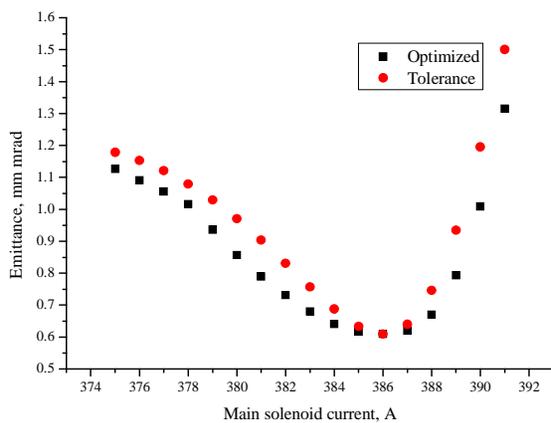
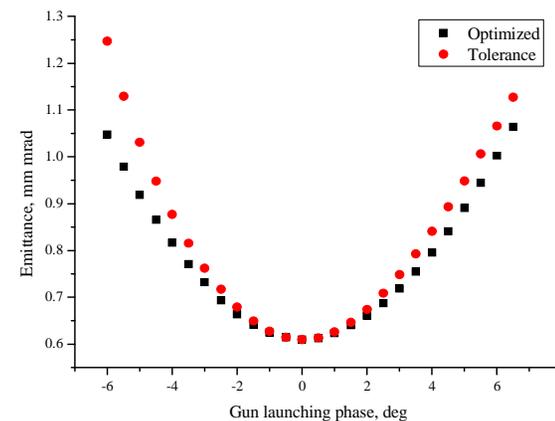
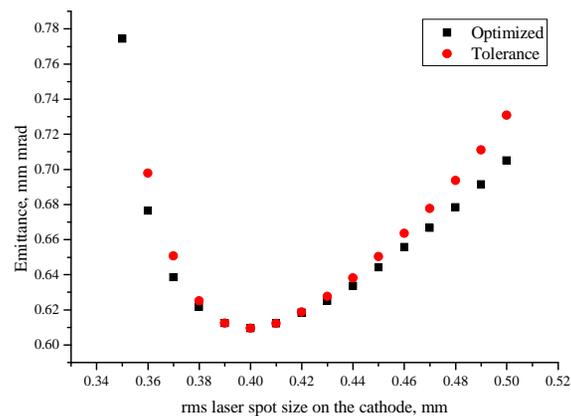
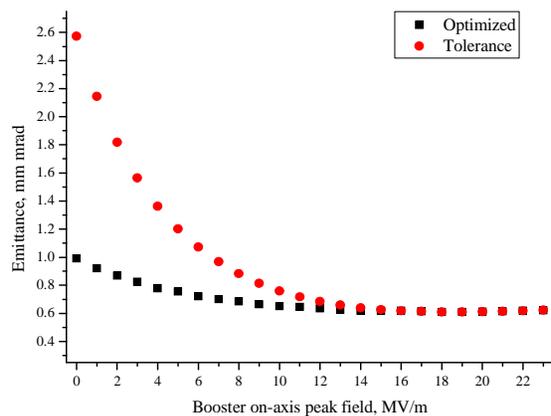


EMSY1 – optimization point –
5.74 m downstream from the
cathode

Optimization parameters

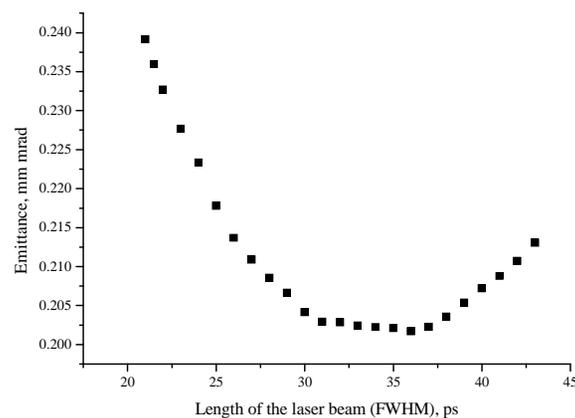
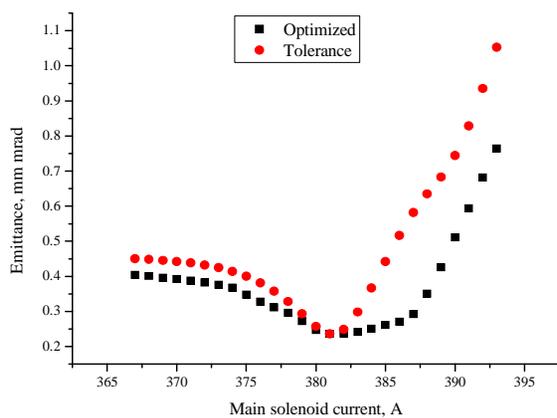
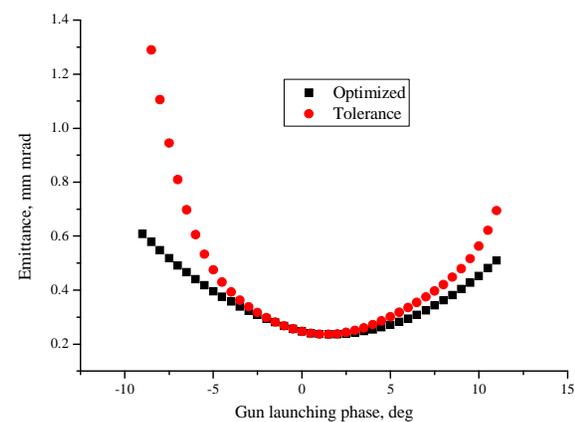
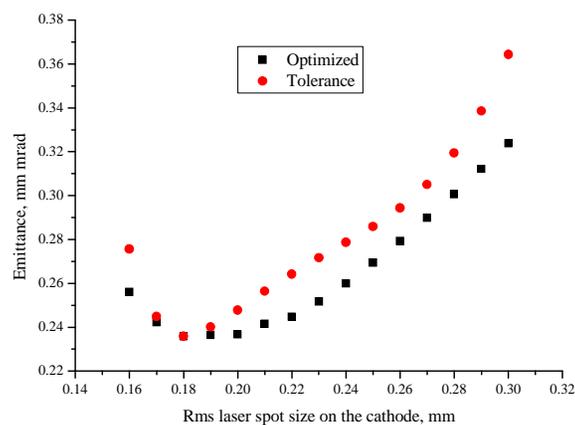
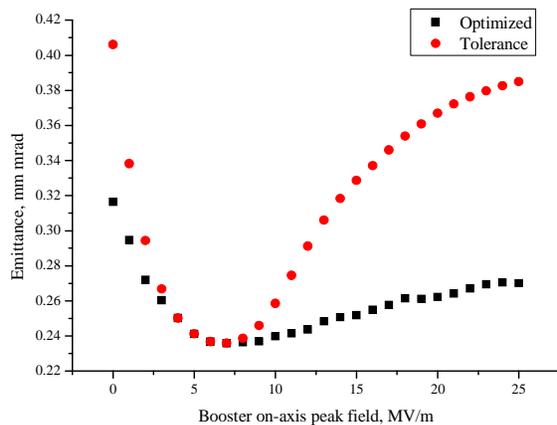
Parameter	Value	Value	Value	Value	Value	Unit
Bunch charge	1	0.25	0.1	0.02	2	nC
Flat top laser temporal profile, FWHM	[20;45]	[20;45]	[20;45]	[14;40]	[20;45]	ps
Flat top laser temporal profile, rt/ft	2	2	2	2	2	ps
Uniform laser transverse profile, rms	[0.35;0.6]	[0.15;0.3]	[0.09;0.21]	[0.035;0.11]	[0.55;0.71]	mm
Gun on-axis peak field	61	61	61	61	61	MV/m
Gun phase w.r.t. MMMG phase	[-8;8]	[-8;8]	[-8;8]	[-8;8]	[-8;8]	Deg
Main solenoid current	[370;400]	[360;400]	[360;400]	[360;400]	[360;400]	A
Booster on-axis peak field	[0;25]	[0;25]	[0;25]	[0;25]	[0;25]	MV/m
Booster phase w.r.t. MMMG phase	0	0	0	0	0	deg

Emittance for 1nC bunch charge.



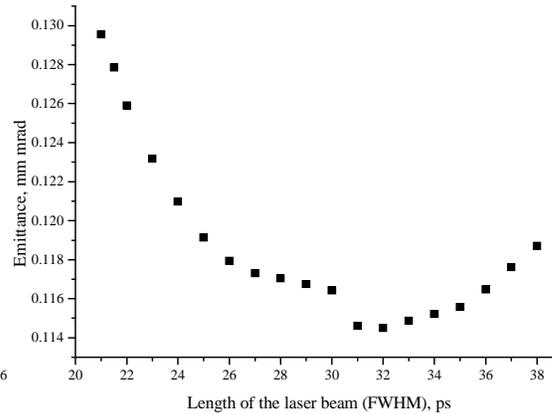
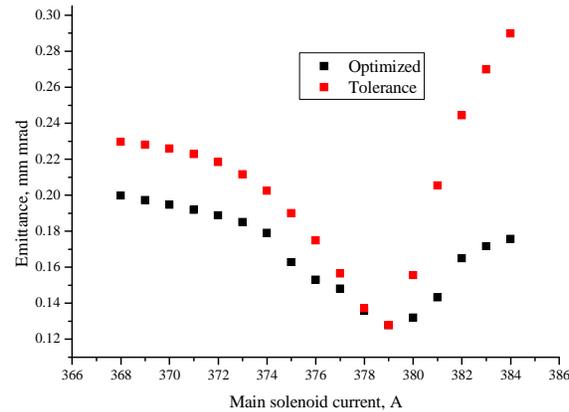
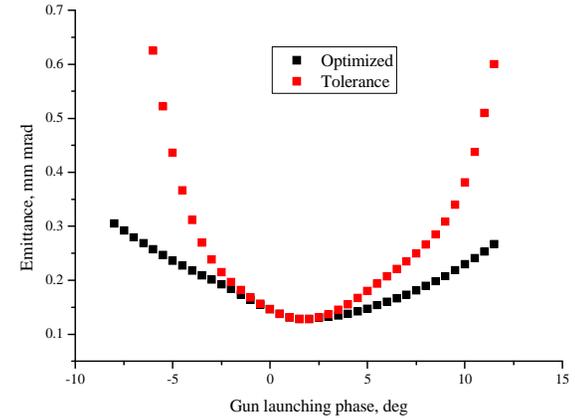
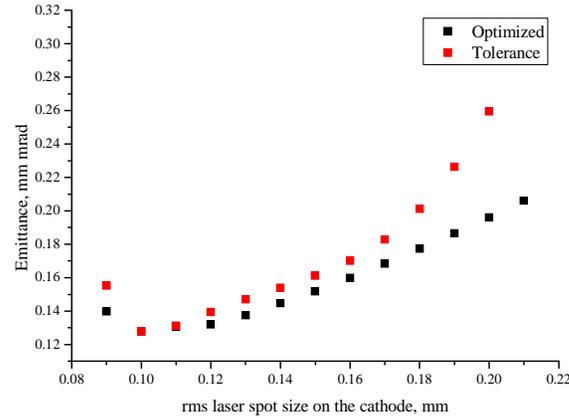
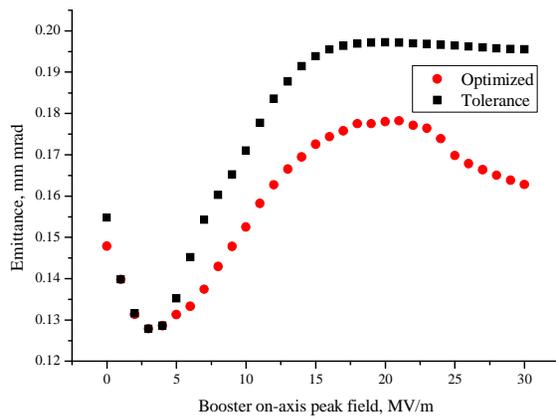
Parameter	Value
ϵ , mm mrad	0.61
σ , mm	0.4
I , A	386
φ , deg	0
E_b , MV/m	19

Emittance for 250pC bunch charge.



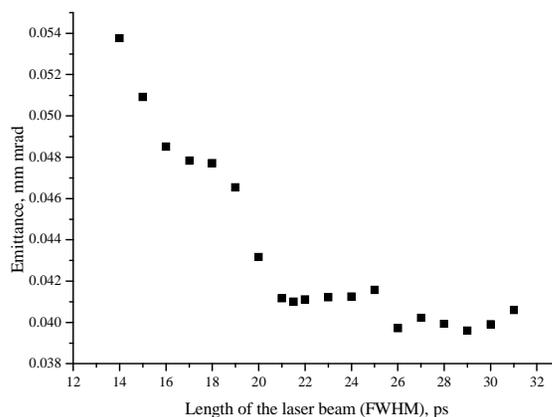
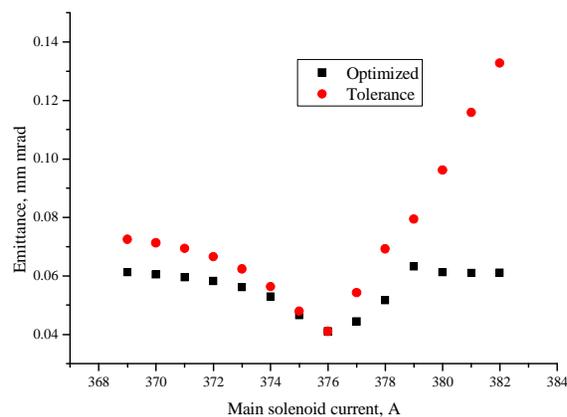
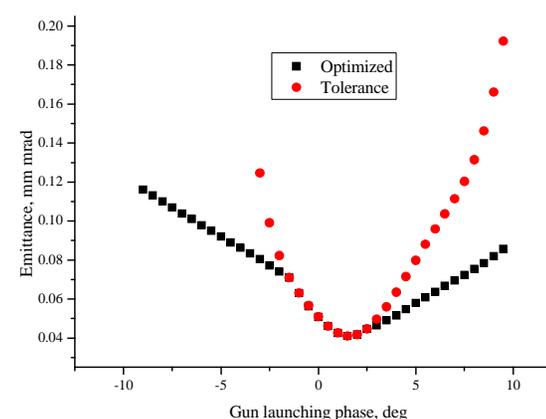
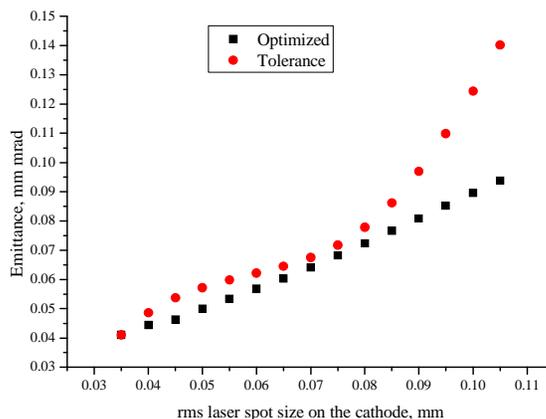
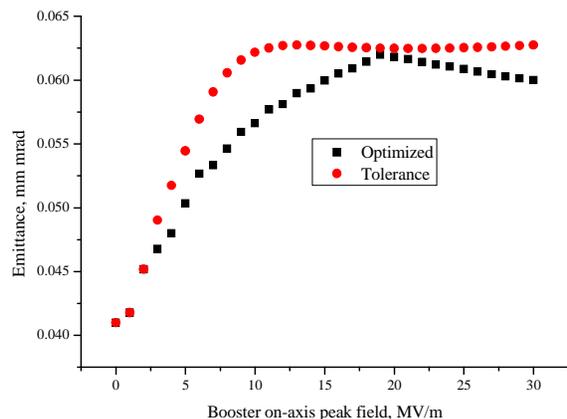
Parameter	Value
ϵ , mm mrad	0.24
σ , mm	0.18
I , A	381
φ , deg	1.5
E_b , MV/m	7

Emittance for 100pC bunch charge.



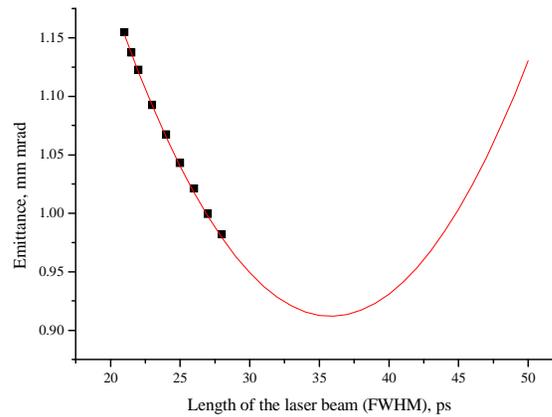
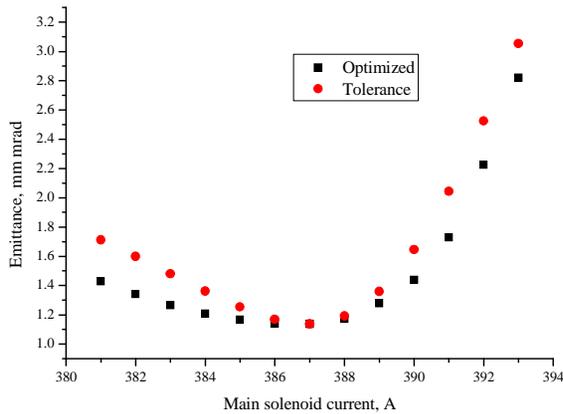
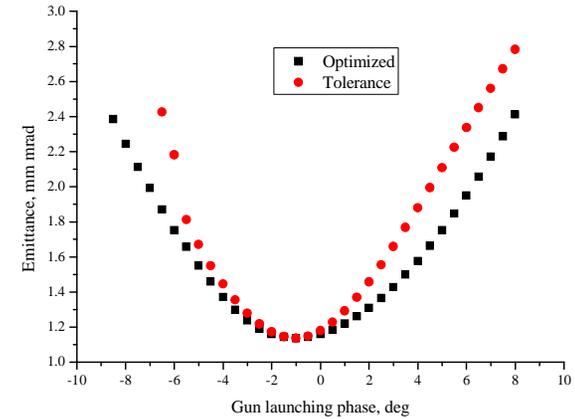
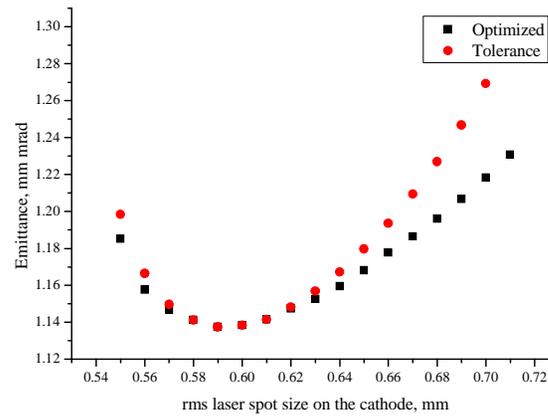
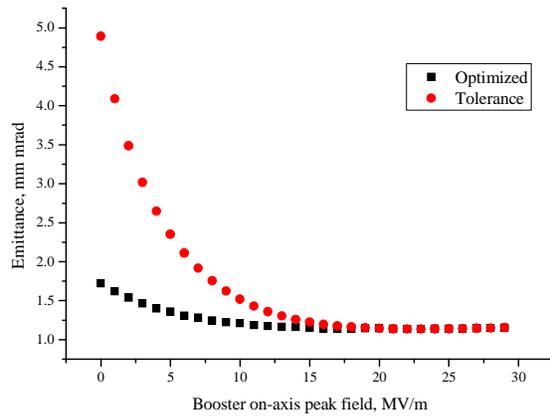
Parameter	Value
ϵ , mm mrad	0.13
σ , mm	0.1
I , A	379
φ , deg	2
E_b , MV/m	3

Emittance for 20pC bunch charge.



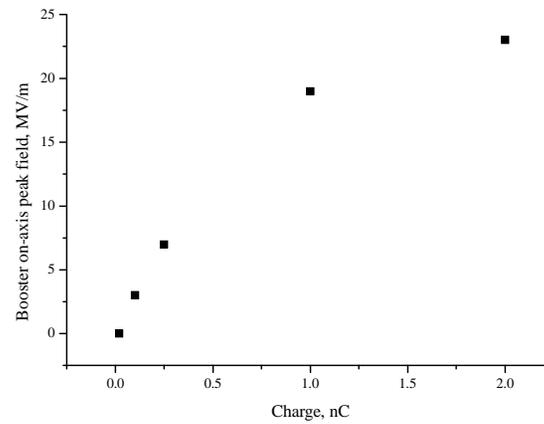
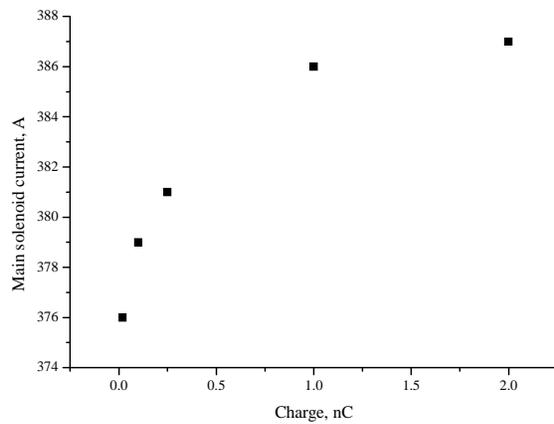
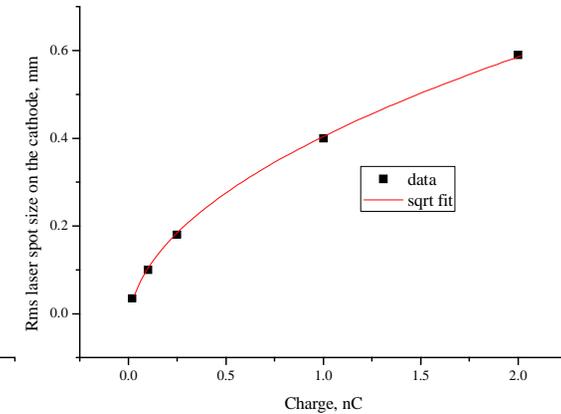
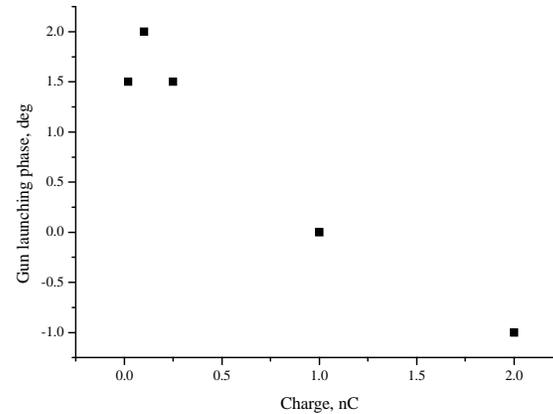
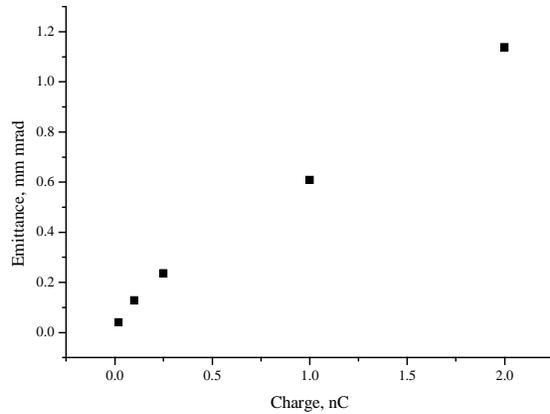
Parameter	Value
ϵ , mm mrad	0.04
σ , mm	0.035
I , A	376
φ , deg	1.5
E_b , MV/m	0

Emittance for 2nC bunch charge.

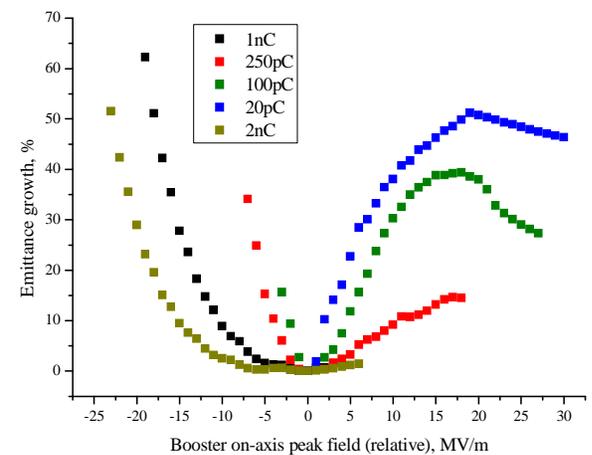
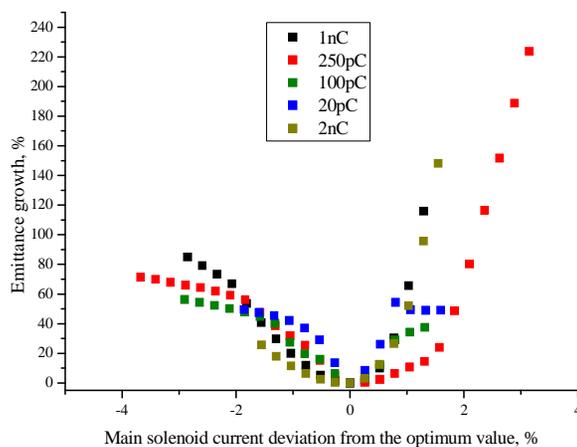
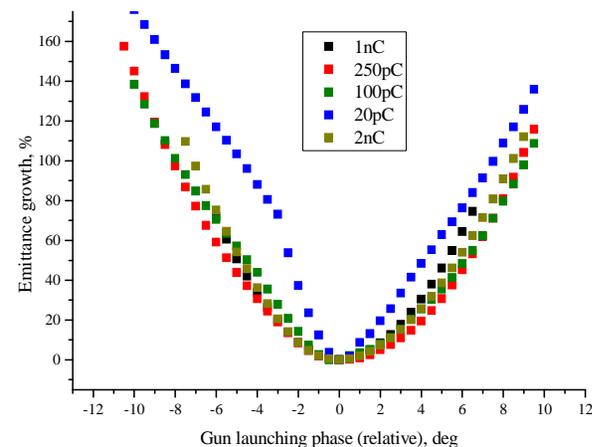
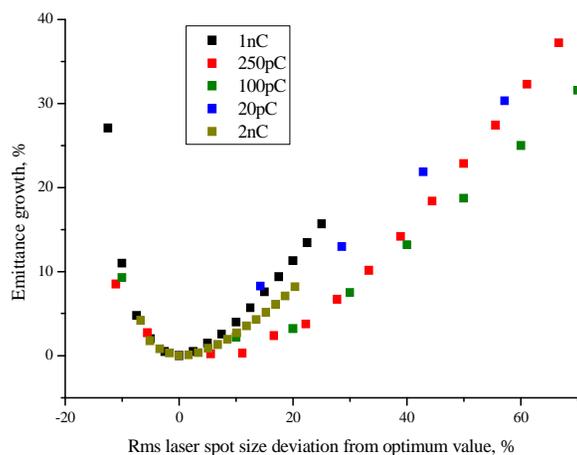


Parameter	Value
ϵ , mm mrad	1.14
σ , mm	0.59
I , A	387
φ , deg	-1
E_b , MV/m	23

Emittance dependence on charge.



Emittance dependencies on different parameters



Systematic errors estimation

- Booster accelerating gradient: $<5\%$ for ± 1 MV/m that corresponds to 800 KeV/c \Rightarrow Experimental precision: <100 KeV/c \Rightarrow neglected.
- Rms laser spot size on the cathode: $<5\%$ for ± 0.1 mm \Rightarrow Experimental precision <0.025 mm \Rightarrow neglected.

Charge	Systematic error, %
2 nC	$<8\%$
1 nC	$<12\%$
250 pC	$<12\%$
100 pC	$<25\%$
20 pC	$<40\%$

Summary

- Detailed simulations for **2nC**, **1nC**, **0.25nC**, **0.1nC** and **0.02nC** bunch charges are performed for a wide range of machine parameters.
- Possible systematic errors during experiments increase with a charge.
- Optimum emittance values at laser pulse length of 21.5 ps are presented in table.

Parameter	2nC	1nC	0.25nC	0.1nC	0.02nC	Unit
ϵ_n	1.14	0.61	0.24	0.13	0.041	mm mrad
ϵ_{th}/ϵ_n	0.44	0.56	0.63	0.65	0.73	
$\langle \epsilon_{slice} \rangle$	1.04	0.57	0.22	0.12	0.037	mm mrad
I_p	80.3	43.1	11.8	4.9	1.0	A

Thank You for attention.

